

GTR Module

Silicon N Channel IGBT

High Power Switching Applications

Motor Control Applications

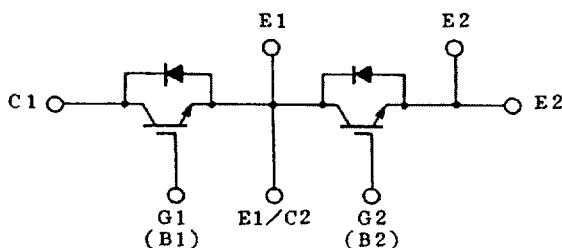
Features

- High input impedance
- High speed: $t_f = 1.0\mu s$ (Max.)
 $t_{rr} = 0.5\mu s$ (Max.)
- Low saturation: $V_{CE(sat)} = 2.7V$ (Max.)
- Enhancement mode
- The electrodes are isolated from case
- Includes a complete half bridge card in one package

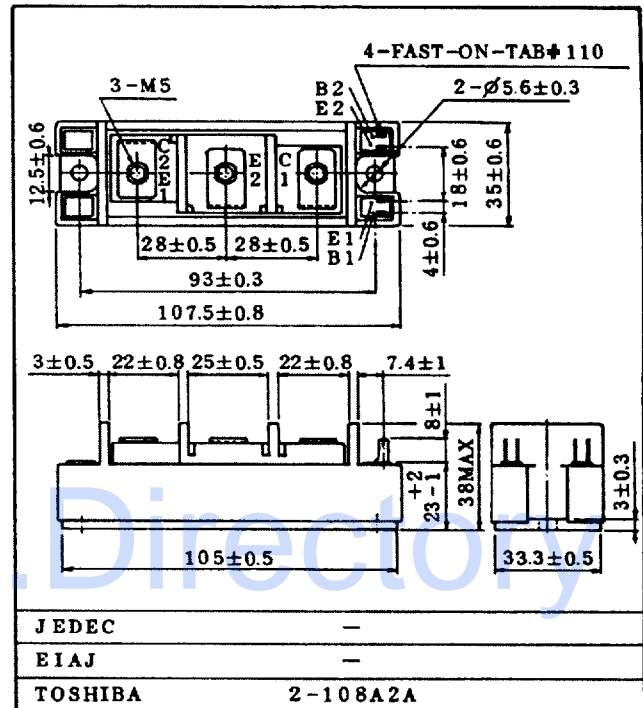
Maximum Ratings (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Emitter Voltage	V_{CES}	1200	V
Gate-Emitter Voltage	V_{GES}	± 20	V
Collector Current	DC	I_C	75
	1ms	I_{CP}	150
Forward Current	DC	I_F	75
	1ms	I_{FM}	150
Collector Power Dissipation (Tc = 25°C)	P_C	600	W
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	-40 ~ 125	°C
Isolation Voltage	V_{isol}	2500 (AC 1 min.)	V
Screw Torque (Terminal/Mounting)	—	3/3	N·m

Equivalent Circuit



Unit in mm



Weight : 240g

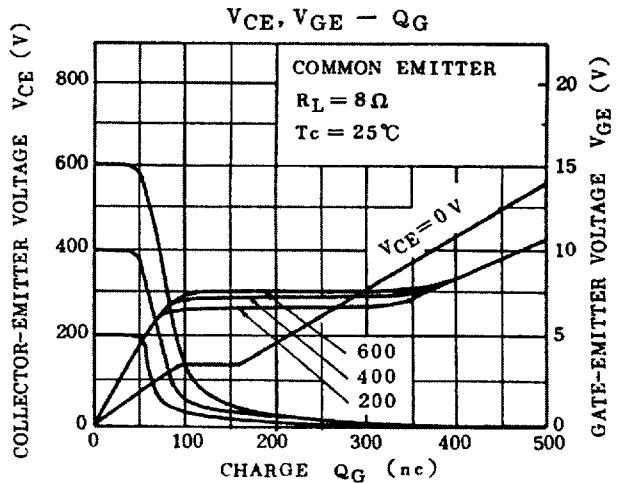
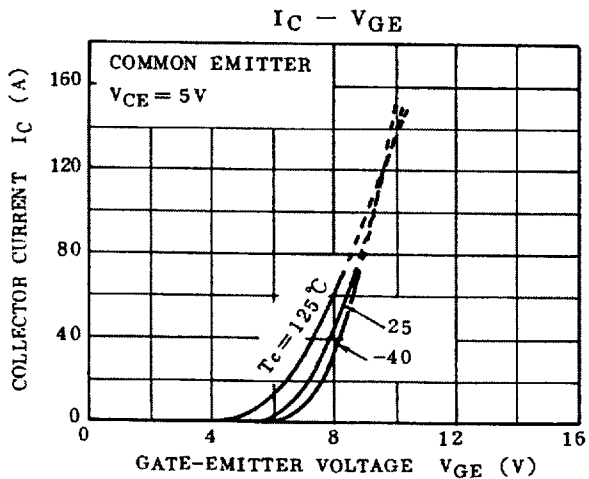
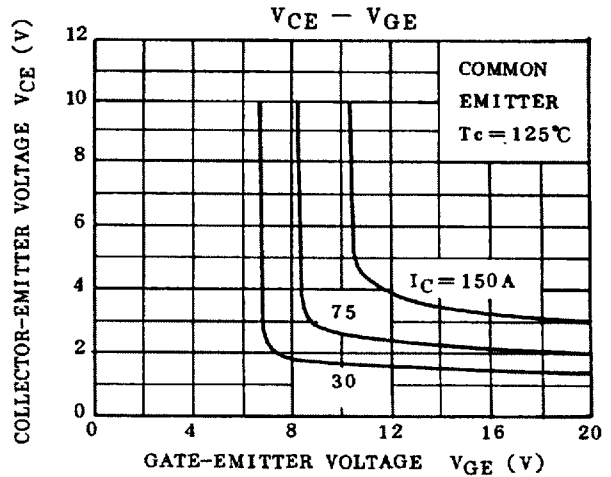
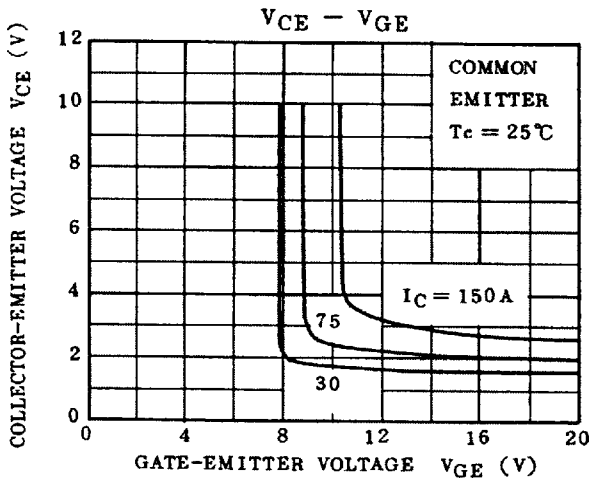
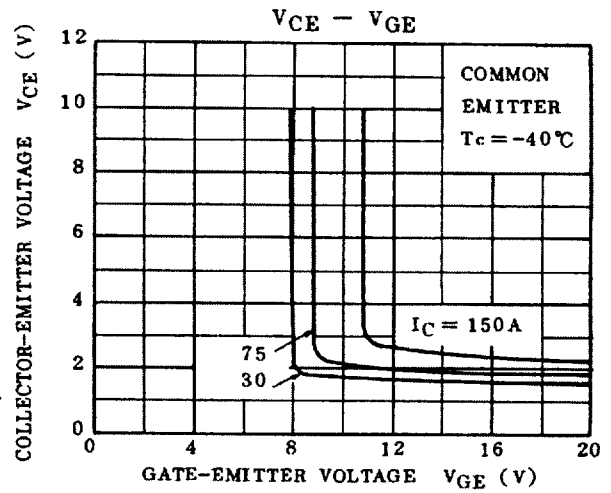
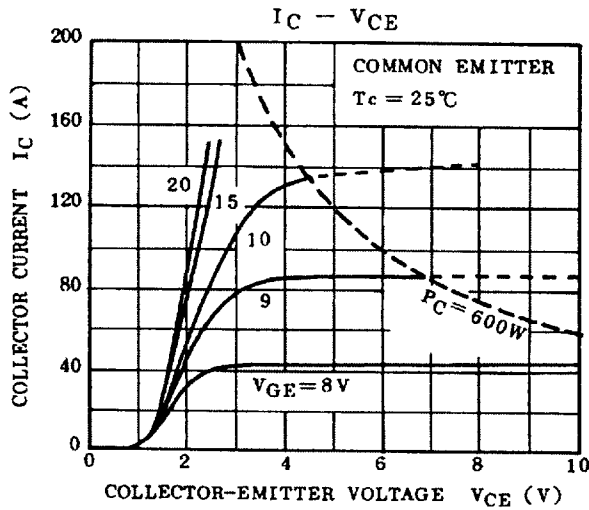
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Electrical Characteristics (Ta = 25°C)

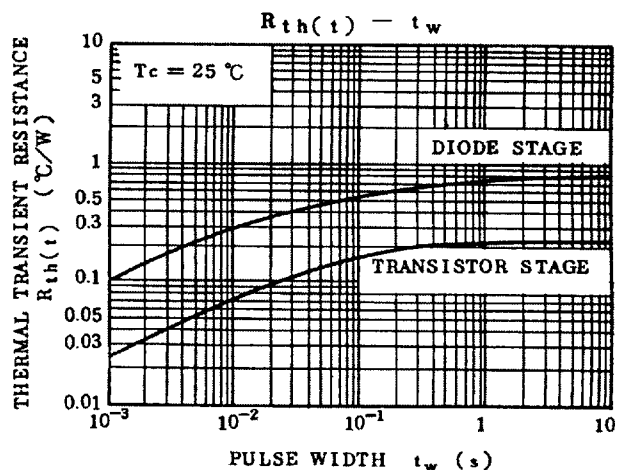
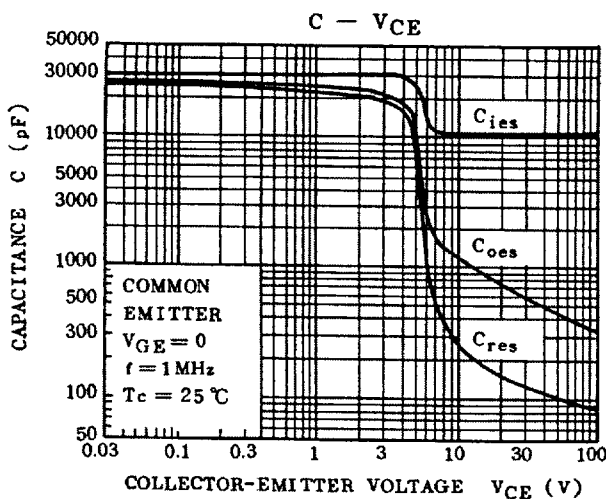
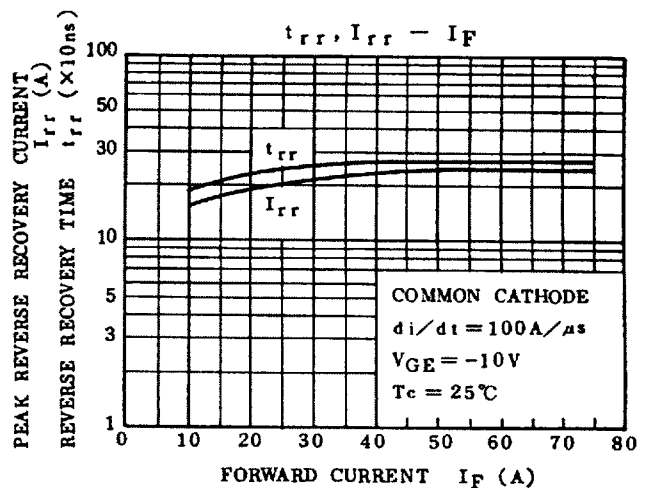
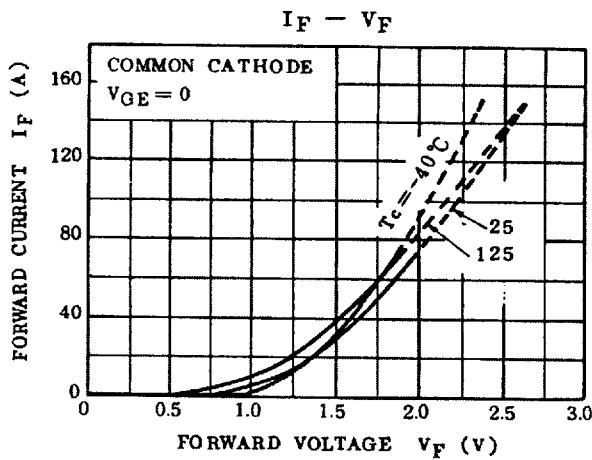
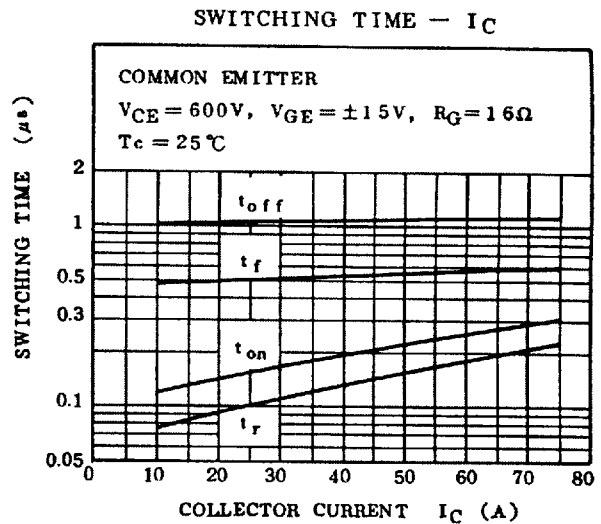
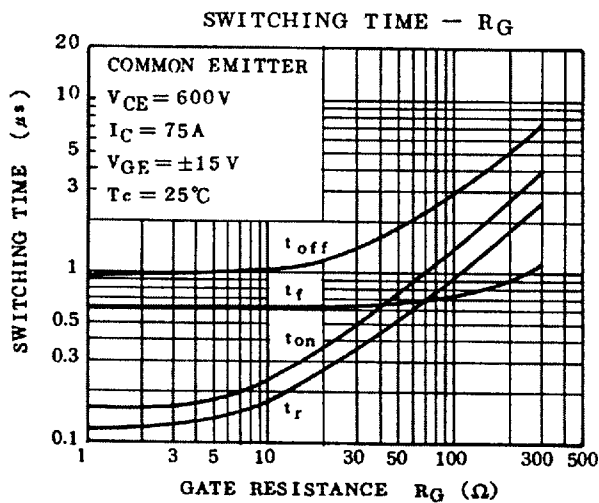
CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Gate Leakage Current		I_{GES}	$V_{GE} = \pm 20V, V_{CE} = 0$	—	—	± 500	nA
Collector Cut-off Current		I_{CES}	$V_{CE} = 1200V, V_{GE} = 0$	—	—	1.0	mA
Collector-Emitter Voltage		V_{CES}	$I_C \leq 1mA, V_{GE} = 0$ Note 1	1200	—	—	V
Gate-Emitter Cut-off Voltage		$V_{GE(OFF)}$	$I_C = 75mA, V_{CE} = 5V$	3.0	—	6.0	V
Collector-Emitter Saturation Voltage		$V_{CE(sat)}$	$I_C = 75A, V_{GE} = 15V$	—	2.2	2.7	V
Input Capacitance		C_{ies}	$V_{CE} = 10V, V_{GE} = 0, f = 1MHz$	—	10000	—	pF
Switching Time	Rise Time	t_r		—	0.3	0.6	μs
	Turn-on Time	t_{on}		—	0.4	0.8	
	Fall Time	t_f		—	0.6	1.0	
	Turn-off Time	t_{off}		—	1.2	1.8	
Forward Voltage		V_F	$I_F = 75A, V_{GE} = 0$	—	2.0	3.0	V
Reverse Recovery Time		t_{rr}	$I_F = 75A, V_{GE} = -10V$ $di/dt = 100A/\mu s$	—	0.25	0.5	μs
Thermal Resistance		$R_{th(j-c)}$	Transistor	—	—	0.208	°C/W
			Diode	—	—	0.8	

Note 1 : Do not apply the over rating voltage.

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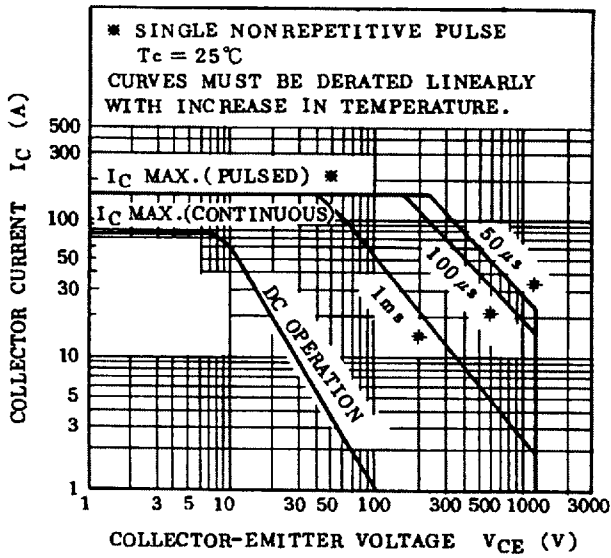


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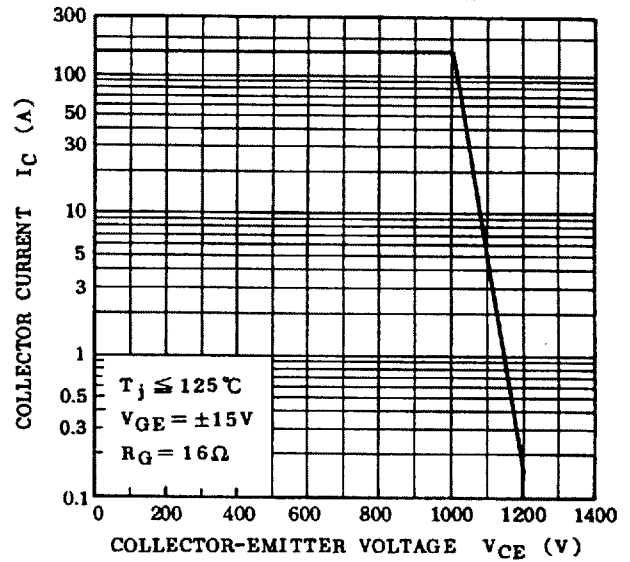


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